

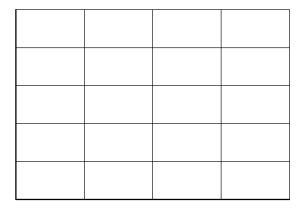


Figure 1. Bare Die Dimensions

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise stated)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = 1 mA	1200	_	-	V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	I _D = 1 mA, referenced to 25°C	-	600	-	mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 1200 V, T _J = 25°C	-	_	100	μΑ
		V _{GS} = 0 V, V _{DS} = 1200 V, T _J = 175°C	_	·	-	

TYPICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted) (continued)



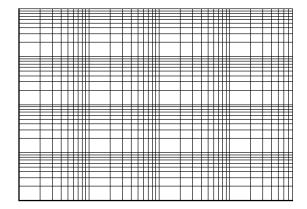
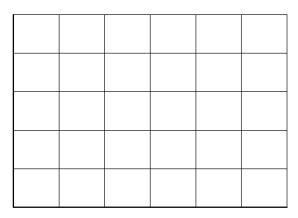
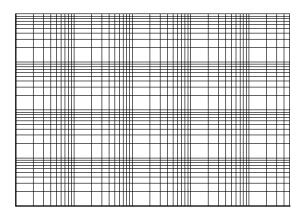
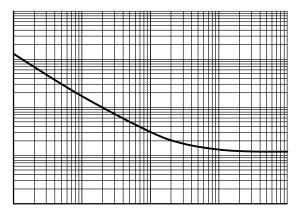


Figure 8. Gate-tore 8. Gate







TYPICAL CHARACTERISTICS ($T_J = 25$ °C unless otherwise noted) (continued)

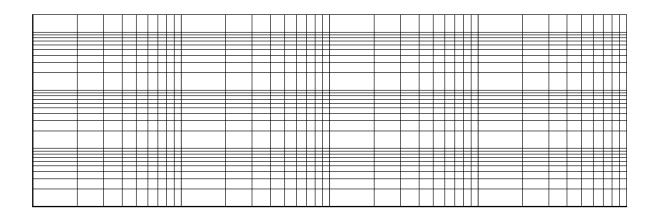


Figure 14. Junction-to-Ambient Thermal Response

